

can be controlled by *electrochemical gating* [1,2]. Based on density functional theory calculations, we show that molecules under study behave as weakly coupled quantum dots, where the current is carried by a redox-active LUMO-(lowest unoccupied molecular) level [3]. We calculate how the conductance decays with increasing the wire length and thereby recover quantitatively the experimental tunneling exponent [4]. Our calculations imply, that the charging induced conformational change in the bipyridinium unit is not a main switching agent, rather than the phonon-assisted inelastic electron transport through the viologen redox-level explains the observed switching behavior [3].

[1] W. Haiss *et al.*, J. Am. Chem. Soc. **125**, 15294 (2003). [2] Zh. Li *et al.*, Nanotechnology, **18**, 044018 (2007). [3] A. Bagrets, A. Arnold, and F. Evers, arXiv:0711.XXXXv1. [4] Ch. Li, I. Pobelov, Th. Wandlowski, A. Bagrets, A. Arnold, and F. Evers, to appear in J. Am. Chem. Soc.

TT 14.2 Tue 9:45 H 3010

Effects of polaron hopping on the transport through DNA — ●BENJAMIN B. SCHMIDT^{1,2}, MATTHIAS H. HETTLER², and GERD SCHÖN^{1,2} — ¹Institut für Theoretische Festkörperphysik, Universität Karlsruhe, 76128 Karlsruhe, Germany — ²Forschungszentrum Karlsruhe, Institut für Nanotechnologie, Postfach 3640, 76021 Karlsruhe, Germany

Experiments probing the equilibrium transport in DNA [1] have led to the consensus that polaron hopping is the dominant transport mechanism of charge carriers in DNA. On the other hand in non-equilibrium experiments where short DNA molecules are connected to two biased leads various types of behaviour is seen (reaching from ballistic transport to insulating behaviour). The reason for this discrepancy is not resolved. We suggest that polaron hopping plays an important role in the non-equilibrium transport through DNA. Our theory is based on work by Böttger and Bryksin [2] on small polaron transport in bulk materials, which we extend to nanostructures where we also account for coupling of the DNA to the leads. It describes the polaron hopping quantum mechanically by expanding the time evolution of the occupation number on the different bases along the Keldysh contour. We observe non-symmetric current-voltage characteristics which we relate to partial charge redistribution on the DNA due to the applied bias.

[1] P.Henderson *et al.*, PNAS USA, **96**, 8353 (1999)

[2] H. Böttger and V. V. Bryksin, 'Hopping conduction in Solids', Akademie Verlag Berlin, (1985)

TT 14.3 Tue 10:00 H 3010

Dynamical effects in the conductance properties of short DNA molecular wire: a combined study using molecular dynamics and model Hamiltonians — ●RODRIGO CAETANO¹, RAFAEL GUTIERREZ¹, BEN WOICZIKOWSKI², TOMAS KUBAR², MARCUS ELSTNER², and GIANAURELIO CUNIBERTI¹ — ¹Institute for Materials Science and Max Bergmann Center for Biomaterials, Dresden University of Technology, D-01062 Dresden, Germany — ²Institute for Physical and Theoretical Chemistry, Braunschweig University of Technology, D-38106 Braunschweig, Germany

The potential applications of DNA either as template or as molecular wires make of crucial importance to understand the microscopic mechanism leading supporting (or hindering) charge migration through this molecule. The experimental studies give very striking results, which range from insulating up to superconducting behavior. Theoretically, it is very important to include dynamical effects, since DNA is known to be a very flexible molecule. The dynamical effects of the solvent should be taken into account. In this work, we study charge transport through short Poly(G)-Poly(C) DNA within a minimal tight binding model. The model parameters are extracted from snapshots along QM/MM trajectories via DFTB approximation and thus include internal and solvent dynamical effects. We perform a statistical analysis of the time-dependent onsite and electronic hopping and show a broad non symmetric distribution. Green function formalism is used to calculate the transport characteristics and demonstrate how the average quantities depend on the relation between system time scales.

TT 14.4 Tue 10:15 H 3010

Switching response of DNA conduction under stretching — ●BO SONG¹, MARCUS ELSTNER², and GIANAURELIO CUNIBERTI¹ — ¹Institute for Materials Science, Dresden University of Technology, D-01062 Dresden, Germany — ²Institute for Physical and Theoretical Chemistry, Braunschweig University of Technology, D-38106 Braunschweig, Germany

By merging DFTB calculations and model-Hamiltonian approaches, we study the stretching-twisting process of poly(GC) DNA oligomers. A local maximum for the transfer integral t between two nearest-neighbor GC pairs is found in the stretching process, which arises from the competition between stretching and twisting. This results in a local maximum for the current in the case that the electrode-DNA coupling Γ is greater than t . Reducing Γ to the values smaller than t gives rise to plateaus in the current. The heights of such plateaus are almost equal to each other.

TT 14.5 Tue 10:30 H 3010

Modeling of tunneling through single endohedral N@C₆₀ molecules — ●CARSTEN TIMM¹, JACOB E. GROSE², WOLFGANG HARNEIT³, and DANIEL C. RALPH² — ¹University of Kansas, Lawrence, USA — ²Cornell University, Ithaca, USA — ³Freie Universität Berlin, Germany

We report on recent experimental and theoretical results for single-molecule transistors involving endohedral N@C₆₀ fullerene molecules. In this talk, we will focus on the theoretical modeling. The observed differential conductance shows strong evidence for the exchange interaction between electrons in the fullerene LUMO and the nitrogen p-electrons, favoring an antiferromagnetic interaction. In addition, soft vibrational modes are seen, which are attributed to oscillations of the molecule as a whole. We discuss a model Hamiltonian that reproduces the main features of the experimental conductance.

TT 14.6 Tue 10:45 H 3010

Silicon based nanogap devices for transport studies on molecule-nanoparticle junctions — ●SEBASTIAN STROBEL¹, ROCIO MURCIA¹, ALLAN HANSEN², and MARC TORNOW² — ¹Walter Schottky Institut, TU München, Germany — ²Institut für Halbleitertechnik, TU Braunschweig, Germany

One possible realization of future nanoelectronics may be a hybrid combination of existing silicon circuitry with functional molecular units. Such approach requires a silicon based technology that allows for the parallel fabrication of contact structures for molecules, as well as the fundamental characterization of such hybrids.

We have fabricated arrays of individually addressable nanogap electrodes with a predefined separation down to ~20 nm using silicon on insulator (SOI) as substrate material. The samples were processed using standard optical lithography, dry and wet chemical etching, and metal thin film deposition, only.

We realized hybrid molecular junctions using such nanogap electrode devices by self-assembling a monolayer of mercaptohexanol onto the metal contacts, and trapping 30 nm diameter Au nanoparticles between the functionalized electrodes, subsequently. Transport measurements at 4.2 K revealed pronounced Coulomb staircase behaviour, characteristic for asymmetric double-barrier tunnelling junctions. We analyse our data by means of model calculations.

TT 14.7 Tue 11:00 H 3010

Length-dependent conductance and thermopower in metal-molecule-metal junctions — ●JANNE VILJAS^{1,2}, FABIAN PAULY¹, and JUAN CARLOS CUEVAS^{3,1,2} — ¹Institut für Theoretische Festkörperphysik and DFG-Center for Functional Nanostructures, Universität Karlsruhe, D-76128 Karlsruhe — ²Forschungszentrum Karlsruhe, Institut für Nanotechnologie, D-76021 Karlsruhe — ³Departamento de Física Teórica de la Materia Condensada C-V, Universidad Autónoma de Madrid, E-28049 Madrid, Spain

Using a method based on density-functional theory, we investigate the conductance and the thermopower in metal-molecule-metal junctions made of dithiolated oligophenylenes contacted to gold electrodes [1]. We find that while the conductance decays exponentially with increasing molecular length, the thermopower increases linearly in good quantitative agreement with recent experiments [2]. We also analyze how these transport properties can be tuned with methyl side groups. The characteristic substituent effects in our ab-initio calculations are explained using a π -electron tight-binding model, which we have studied in detail.

[1] F. Pauly, J. K. Viljas, and J. C. Cuevas, arXiv:0709.3588.

[2] P. Reddy *et al.*, Science **315**, 1568 (2007).

15 min. break

TT 14.8 Tue 11:30 H 3010

Current switching in single molecule transport and con-

tact — ●VELIMIR MEDED, ALEXEJ BAGRETS, ANDREAS ARNOLD, and FERDINAND EVERS — Institute of Nanotechnology, Research Centre Karlsruhe, Hermann-von-Helmholtzplatz 1, 76344 Eggenstein-Leopoldshafen, Germany

Two experiments measuring the current-voltage characteristics (IV) of the bipyridine-dinitro-dithiole-system found that the molecule can be controllably switched between two states exhibiting significantly different IV curves [1,2]. To better understand the nature of the bistable state we have performed ab initio calculations. They indicate, that molecular charging/uncharging does not lead to bistability in the presence of electrodes. By contrast, two (or more) energy minima can arise with conformational changes of the molecule alone or in the molecule-contact region (possibly combined with structural relaxations in a larger contact area). As a prototypical example of such a mechanism, we consider rotations of the molecule about the axis defined by the two anchoring Au-atoms. From an extensive analysis of possible contact structures, we conclude that bistable configurations can indeed arise for slightly disordered, i.e. realistic, contacts – though they do not appear to be generic. A scenario will be proposed, how in this light experimental findings might be understood. (We are indebted to E. Loertscher, H. Riel and M. Ruben for instructive discussions.)

[1] Z. K. Keane, J. W. Ciszek, J. M. Tour, and D. Natelson, *Nano Lett.*, Vol. 6, No. 7, 2006. [2] E. Lörtscher, J. W. Ciszek, J. Tour, and H. Riel, *Small* 2, 973 (2006).

TT 14.9 Tue 11:45 H 3010

Temperature dependence of the conductance in biphenyl-dithiol single-molecule junctions — ●FABIAN PAULY¹, JANNE VILJAS^{1,2}, JUAN CARLOS CUEVAS³, and GERD SCHÖN^{1,2} — ¹Institut für Theoretische Festkörperphysik and DFG-Center for Functional Nanostructures, Universität Karlsruhe, 76128 Karlsruhe, Germany — ²Forschungszentrum Karlsruhe, Institut für Nanotechnologie, 76021 Karlsruhe, Germany — ³Departamento de Física Teórica de la Materia Condensada, Universidad Autónoma de Madrid, 28049 Madrid, Spain

Using a density-functional-based transport method, we study the conduction properties of several biphenyl-derived dithiol (BPDDT) molecules wired to gold electrodes [1]. The BPDDT molecules differ in their side groups, which control the degree of conjugation of the π -electron system. We have analyzed the dependence of the low-bias zero-temperature conductance on the tilt angle φ between the two phenyl ring units, and find that it follows closely a $\cos^2(\varphi)$ law as observed in a recent experiment [2].

In addition, we study the temperature dependence of both the conductance and its fluctuations and find qualitative differences between the examined molecules. We illustrate that the fluctuations of the conductance due to temperature-induced changes in the geometric structure of the molecule can be reduced by an appropriate design.

[1] F. Pauly, J. K. Viljas, J. C. Cuevas, G. Schön, arXiv:0705.3285.

[2] Venkataraman *et al.*, *Nature* 442, 904 (2006).

TT 14.10 Tue 12:00 H 3010

Symmetry effects in transport properties of benzene quantum dots — ●GEORG BEGEMANN, DANA DARAU, ANDREA DONARINI, and MILENA GRIFONI — Theoretische Physik, Universität Regensburg

We investigate electronic transport through a benzene molecule quantum dot. In particular, we investigate the influence of the contacts' position and find qualitative and quantitative differences between the para- and the meta configurations.

The Hamiltonian of the interacting isolated molecule is diagonalized and its eigenstates are classified according to their particle number, spin and symmetry representation.

Treating the coupling to the leads perturbatively, a generalized master equation for the reduced density matrix in the benzene's eigenbasis is derived, which includes coherences between degenerate eigenstates. We explicitly demonstrate that the coherences do not contribute to the linear transport, but become essential for the meta-configuration in the nonlinear regime.

Analytic expressions for the linear conductance and the current in

the low bias regime agree with numeric calculations, where we are not restricted to small voltages. Interesting features appear over a wide range of gate and bias voltages, for example, due to the reduced symmetry of the problem, negative differential conductance is present in the meta-configuration, while it is absent in the para-configuration.

TT 14.11 Tue 12:15 H 3010

Vibrational Effects in Electron Transport through Molecular Junctions — ●RAINER HÄRTLE, CLAUDIA BENESCH, and MICHAEL THOSS — Institut für Theoretische Chemie, Technische Universität München, D-85747 Garching, Germany

We investigate theoretically the role of vibrations in electron transport through single molecule junctions. The study is based on a generic model, which describes steady-state transport through a single molecule that is attached to metal leads. To address multidimensional vibrational dynamics in molecular junctions, we have extended the non-equilibrium Green function approach established by M. Galperin *et al.* to multiple modes. We demonstrate the effect of electronically induced coupling between different vibrational modes and study the stability of these junctions by calculating the vibrational excitations as a function of the bias voltage. In addition to a model system with two vibrational degrees of freedom, we present results for *p*-benzenedi(butanethiolate) covalently bound to gold electrodes.

TT 14.12 Tue 12:30 H 3010

Quantum fluctuations and vibration-assisted transport through single molecule transistors — ●MARTIN LEIJNSE^{1,2}, MAARTEN WEGEWIJS^{1,2}, and HERBERT SCHOELLER¹ — ¹Institut für Theoretische Physik A, RWTH Aachen, 52056 Aachen, Germany — ²Institut für Festkörper-Forschung - Theorie 3, Forschungszentrum Jülich, 52425 Jülich, Germany

Non-equilibrium transport through a single molecule transistor is studied in the presence of strong coupling to a local vibrational mode. Employing a full fourth order perturbation expansion in the tunneling Hamiltonian, we address the experimentally relevant regime of intermediate tunneling coupling between molecule and electrodes. Using the real-time transport theory we calculate the nonlinear conductance, accounting for the so-called cotunneling contributions, as well as renormalization and broadening effects, induced by charge fluctuations. We find that broadening and in-elastic cotunneling processes are of comparable importance for the lifting of the vibration-induced Franck-Condon blockade. Strikingly, novel transport features connected to this broadening are found below the bias-voltage threshold for in-elastic cotunneling, which have gone unnoticed until now. Relaxation of the vibrational distribution, induced by coupling to an external phonon bath, leads to a uniform reduction of all higher order processes, i.e. broadening and in-elastic effects remain comparable.

TT 14.13 Tue 12:45 H 3010

Charge-memory effect in molecular junctions — ●PINO D'AMICO¹, DMITRY A. RYNDYK¹, GIANAURELIO CUNIBERTI², and KLAUS RICHTER¹ — ¹Institut für Theoretical Physics, University of Regensburg, D-93040 Regensburg, Germany — ²Max Bergmann Centre for Biomaterials, Dresden University of Technology, D-01062 Dresden, Germany

Charge-memory effects such as bistability and switching between a charged and a neutral state, have been recently observed in an increasing number of experiments on charge transport through molecules [1,2]. We consider a charge-memory effect in the framework of a minimal polaron model. It is shown that in the case of strong electron-vibron interaction the rate of spontaneous quantum switching between two metastable states is exponentially suppressed at zero bias voltage, while remaining large enough at finite voltage. The switching between states at finite voltage and hysteretic charge-voltage curves are calculated at weak coupling to the leads by the master equation method, and at stronger coupling to the leads by the equation-of-motion method for nonequilibrium Green functions.

[1] Jascha Repp *et al.*, *Science*, vol 35, 493-495 (2004)

[2] F. E. Olsson *et al.*, *PRL*, vol 98, 176803 (2007)